M.I.E.T. ENGINEERING COLLEGE, TRICHY-07 DEPARTMENT OF SCIENCE & HUMANITIES PH3251 – MATERIALS SCIENCE (R2021)

QUESTION BANK

<u>UNIT – I -CRYSTALLOGRAPHY</u>

PART-A

- 1. What are the differences between crystalline and non-crystalline materials?
- 2. What is unit cell?.
- 3. What are Bravais Lattices?
- 4. What are Miller indices?
- 5. Define Burgers Vector.
- 6. Define Elastic Strain Energy.
- 7. What is plastic deformation?
- 8. Define Slip and Slip system.
- 9. What is polymorphism?
- 10. Define Linear density and Planar density.
- 11. Give the difference between Edge dislocation and Screw dislocation.
- 12. Define Phase and Phase change.
- 13. What is homogeneous nucleation and heterogeneous nucleation?

PART-B

- 1. Explain the Characteristics of BCC and FCC structures with a neat diagram (16)
- 2. Explain the Characteristics of Hexagonal Closely Packed Crystal System (HCP) with a neat diagram. (16)
- 3. Write a short note on point defects (8)
- 4. Explain (i) Edge dislocation (ii) Screw dislocation (iii) Grain Boundary (iv) Twin Boundary (16)
- 5. Write short note on Plastic deformation of materials.(8)
- 6. Write a short note on (i) Polymorphism
 - (ii) Phase changes
- 7. Explain nucleation and growth and explain about (i) Homogeneous nucleation and (ii) Heterogeneous nucleation. (16)

<u>UNIT – II-ELECTRICAL AND MAGNETIC PROPERTIES OF MATERIALS</u> <u>PART-A</u>

- 1. Define the Terms: Drift velocity and Mobility of electron.
- 2. Define Relaxation time and Collision time.
- 3. Define Drift Current Density.

- 4. State Wiedmann-Franz Law and Mention Lorentz Number.
- 5. What is relaxation time and collision time?
- 6. What are the drawbacks of classical free electron theory?
- 7. What is tunneling?
- 8. Define degenerate states.
- 9. What is Fermi Distribution Function?
- 10. Define Fermi level and Fermi Energy.
- 11. What is Periodic Potential?
- 12. What is an effective mass of electron?
- 13. Define Magnetic dipole moment.
- 14. Define the terms: (i) Magnetic Permeability (iv) Magnetic Susceptibility
- 15. What is Bohr Magneton?
- 16. State Curie Weiss law.
- 17. What are quantum interference devices?
- 18. What is Giant magneto resistance (GMR) sensor?

PART-B

- 1. Derive an expression for electrical conductivity and thermal conductivity of conducting Materials. Deduce the Wiedemann Franz law from it.(16)
- 2. Define Fermi Function. Explain the effect of temperature on Fermi function. (8)
- 3. Define density of states. Derive an expression for the density of states in a cubical Metal. (16)
- 4. Write a short note on (i) Electrons in a periodic potential. (8)
 - (ii) Tight binding approximation in solids. (8)
- 5. Derive an expression for the effective mass of an electron and concept of hole. (16)
- 6. Explain the properties of Dia, Para and Ferro magnetic materials. (16)
- 7. Explain Para magnetism in conduction electrons in metals. (8)
- 8. Discuss the Origin and exchange interaction of ferromagnetism.(8)
- 9. Write a short note on quantum interference devices.(8)
- 10. Describe working of GMR devices. (16)

<u>UNIT – III- SEMICONDUCTORS AND TRANSPORT PHYSICS</u>

PART-A

- 1. What are the properties of semiconductors?
- 2. What are the differences between Indirect band gap and Direct band gap semiconductors?
- 3. What are the differences between intrinsic and extrinsic semiconductors?
- 4. What are the differences between n-type and p-type semiconductors?
- 5. Define Drift current and Diffusion current.
- 6. Define Hall effect.

- 7. What are Hall Devices?
- 8. What are the difference between Ohmic diode and Schottky diode?
- 9. What are applications of schottky diode?

PART-B

- 1. Obtain an expression for carrier concentration in an intrinsic semiconductor and also calculate the intrinsic carrier concentration. (16)
- 2. Derive an expression for density of electrons in the conduction band of an n type semiconductor and explain the variation of Fermi level with temperature and donor concentration. (16)
- 3. Derive an expression for density of holes in the valence band of an p type semiconductor and explain the variation of Fermi level with temperature and acceptor concentration. (16)
- 4. Explain the working principle of (i) Gauss Meter (ii) Electronic Multimeter and (iii) Electronic Wattmeter (16)
- 5. Describe the construction and working principle of Ohmic contact diode.(12)
- 6. Describe the construction and working principle of Schottky diode. Give its advantages, disadvantages and applications. (16)

<u>UNIT – IV- OPTICAL PROPERTIES OF MATERIALS</u>

PART - A

- 1. What are Optical materials. Give their types.
- 2. What is absorption of light in semiconductor?
- 3. What is carrier generation and recombination?
- 4. Define Carrier Injection.
- 5. What is optical gain and optical loss?
- 6. What is quantum well?
- 7. What are opto-electronic devices?
- 8. What is (i) photo diode (ii) solar cell?
- 9. What is (i) LED (ii) OLED?
- 10. What is Excitonic state?
- 11. What is Electro optics and Non Linear optics?
- 12. What are modulators?
- 13. What are optical switching devices?
- 14. Define Plasmonics.

PART - B

- 1. Explain different types of optical materials.(8)
- 2. Explain optical absorption and emission in semiconductors.(8)
- 3. Write a short note on charge injection and recombination.(8)
- 4. Write a short note on optical loss and optical gain.
- 5. Explain the principle, construction and working of (i) P-N photo diode (ii) Solar cell(16)

- 6. Explain the construction and working of a (i) LED (ii) OLED.(16)
- 7. Explain the construction and working of a Laser Diode. Give their advantages, Dis advantages and applications. (16)
- 8. Explain optical process in semiconductor devices.(8)
- 9. Write a short note on Excitonic state. (8)
- 10. Explain the working principle of Electro-Optic Modulator.
- 11. Explain the working principle of Self Electro optic Effect Devices (SEED) (16)
- 12. Write a short note on Plasmonics. (12)

<u>UNIT – V- NANOELECTRONIC DEVICES</u>

$\underline{PART - A}$

- 1. What is quantum confinement?
- 2. What is Quantum well and Quantum wire?
- 3. What is Zener Bloch Oscillation?
- 4. What is Resonant tunneling?
- 5. Define quantum interference.
- 6. Define Mesoscopic structure.
- 7. Define Single Electron phenomena.
- 8. Define Coulomb energy and Coulomb Blockade effect.
- 9. What is SET?
- 10. What are semiconductor photonic structure?
- 11. Define 1D,2D and 3D photonic crystal.
- 12. What are active and passive opto-electronic devices?
- 13. Define photo process.
- 14. What is Spintronics?
- 15. What is Carbon Nano Tube? Give their types?
- 16. What are the properties of CNT?
- 17. What are the applications of CNT?

PART - B

- 1. Write a short note on Quantum confinement and Quantum structures. (16)
- 2. Write a short not on Zener Bloch Oscillations.(12)
- 3. Explain about the concept of Resonant tunneling. (12)
- 4. Write a short note on Mesoscopic structures. (8)
- 5. Describe Construction and Working of Single Electron Tansistor ang give their advantages and applications.(16)
- 6. Explain in detail about Semiconductor photonic Structures and their types. (16)
- 7. Explain about active and passive photonic devices. (12)
- 8. Write a short note on photo process. (8)
- 9. Explain in detail about spintronics. (16)
- 10. What are Carbon Nano Tubes? Give their types, properties and applications.